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Team Nexperia

DISCRETE SEMICONDUCTORS

DATA SHEET

PDTA144W series

PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

Product data sheet Supersedes data of 2004 Mar 23 2004 Aug 05



PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTA144W series

FEATURES

- Built-in bias resistors
- · Simplified circuit design
- Reduction of component count
- · Reduced pick and place costs.

APPLICATIONS

- General purpose switching and amplification
- · Inverter and interface circuits
- Circuit driver.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V_{CEO}	collector-emitter voltage	_	-50	V
Io	output current (DC)	_	-100	mA
R1	bias resistor	47	_	kΩ
R2	bias resistor	22	_	kΩ

DESCRIPTION

PNP resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

PRODUCT OVERVIEW

TVDE NUMBER	PAC	KAGE	MARKING CORE	NDN COMPLEMENT	
TYPE NUMBER	PHILIPS	EIAJ	MARKING CODE	NPN COMPLEMENT	
PDTA144WE	SOT416	SC-75	5D	PDTC144WE	
PDTA144WEF	SOT490	SC-89	2E	PDTC144WEF	
PDTA144WK	SOT346	SC-59	46	PDTC144WK	
PDTA144WM	SOT883	SC-101	F8	PDTC144WM	
PDTA144WS	SOT54 (TO-92)	SC-43	TA144W	PDTC144WS	
PDTA144WT	SOT23	_	*43 ⁽¹⁾	PDTC144WT	
PDTA144WU	SOT323	SC-70	*28 ⁽¹⁾	PDTC144WU	

Note

^{1. * =} p: Made in Hong Kong.

^{* =} t: Made in Malaysia.

^{* =} W: Made in China.

PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTA144W series

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	CIMPLIFIED OUTLINE AND CYMPOL	PINNING		
TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PIN	DESCRIPTION	
PDTA144WS	1 R1 R2 3 MAM338	1 2 3	base collector emitter	
PDTA144WE PDTA144WEF PDTA144WK PDTA144WT PDTA144WU	3 1 R1 R2 Top view MDB271	1 2 3	base emitter collector	
PDTA144WM	2 R1 3 Bottom view MDB267	1 2 3	base emitter collector	

PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTA144W series

ORDERING INFORMATION

TYPE NUMBER	PACKAGE						
ITPE NUMBER	NAME	VERSION					
PDTA144WE	_	plastic surface mounted package; 3 leads	SOT416				
PDTA144WEF	_	plastic surface mounted package; 3 leads	SOT490				
PDTA144WK	 plastic surface mounted package; 3 leads 		SOT346				
PDTA144WM	_	leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm	SOT883				
PDTA144WS	_	plastic single-ended leaded (through hole) package; 3 leads	SOT54				
PDTA144WT	_	plastic surface mounted package; 3 leads	SOT23				
PDTA144WU	_	plastic surface mounted package; 3 leads	SOT323				

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	-50	٧
V _{CEO}	collector-emitter voltage	open base	_	-50	V
V _{EBO}	emitter-base voltage	open collector	_	-10	V
VI	input voltage				
	positive		_	+10	V
	negative		_	-40	V
Io	output current (DC)		_	-100	mA
I _{CM}	peak collector current		_	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C;			
	SOT54	note 1	_	500	mW
	SOT23	note 1	_	250	mW
	SOT346	note 1	_	250	mW
	SOT323	note 1	_	200	mW
	SOT416	note 1	_	150	mW
	SOT490	notes 1 and 2	_	250	mW
	SOT883	notes 2 and 3	_	250	mW
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTA144W series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	T _{amb} ≤ 25 °C		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT416	note 1	830	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W

Note

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions.; FR4 with 60 μm copper strip line.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	_	_	-100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$	_	_	-1	μΑ
		$V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$	_	_	-50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_{C} = 0 \text{ A}$	_	_	-110	μΑ
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -5 \text{ mA}$	60	_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}$	_	_	-150	mV
$V_{i(off)}$	input-off voltage	$I_C = -100 \ \mu A; \ V_{CE} = -5 \ V$	_	-1.7	-1.2	V
$V_{i(on)}$	input-on voltage	$I_C = -2 \text{ mA}; V_{CE} = -0.3 \text{ V}$	-4	-2.7	_	V
R1	input resistor		33	47	61	kΩ
<u>R2</u> R1	resistor ratio		0.37	0.47	0.57	
C _c	collector capacitance	$I_E = I_e = 0 \text{ A}; V_{CB} = -10 \text{ V};$ f = 1 MHz	_	_	3	pF

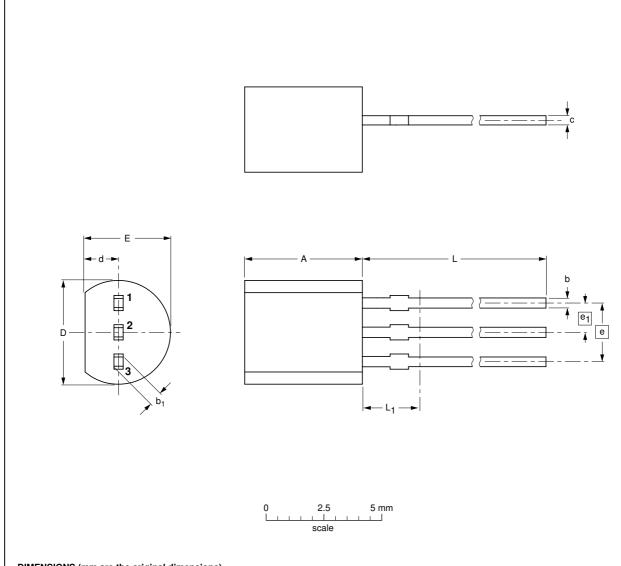
PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTA144W series

PACKAGE OUTLINES

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	Α	b	b ₁	С	D	d	E	е	e ₁	L	L ₁ ⁽¹⁾ max.
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

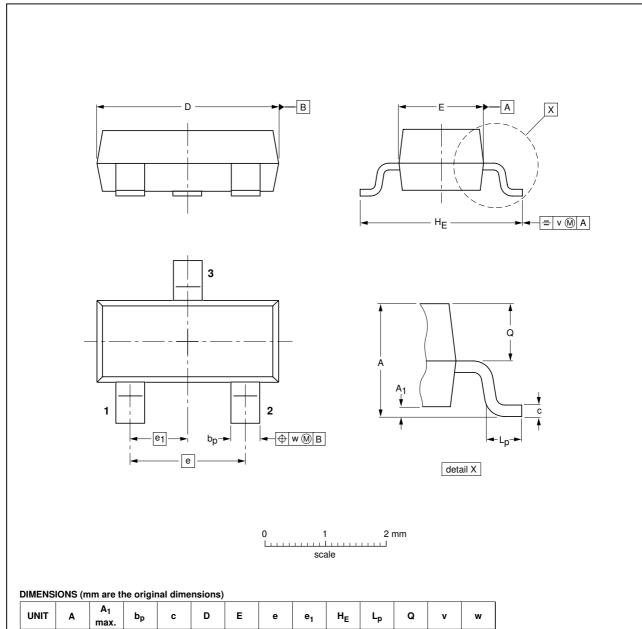
OUTLINE		REFERENCES			EUROPEAN ISSUE DATE			
VERSION	N IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE		
SOT54		TO-92	SC-43A			04-06-28 04-11-16		

PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTA144W series

Plastic surface-mounted package; 3 leads

SOT23



OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA			
SOT23		TO-236AB				-04-11-04- 06-03-16

1.9

0.45

0.55

0.1

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0.48

0.38

0.15

1.1

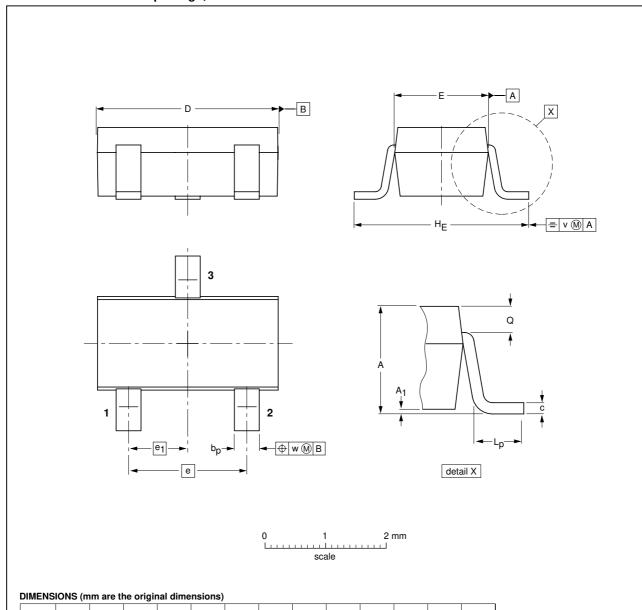
0.9

PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTA144W series

Plastic surface-mounted package; 3 leads

SOT346



UNIT	Α	A ₁	bp	С	D	E	е	e ₁	HE	Lp	Q	v	w
mm	1.3 1.0	0.1 0.013	0.50 0.35	0.26 0.10	3.1 2.7	1.7 1.3	1.9	0.95	3.0 2.5	0.6 0.2	0.33 0.23	0.2	0.2

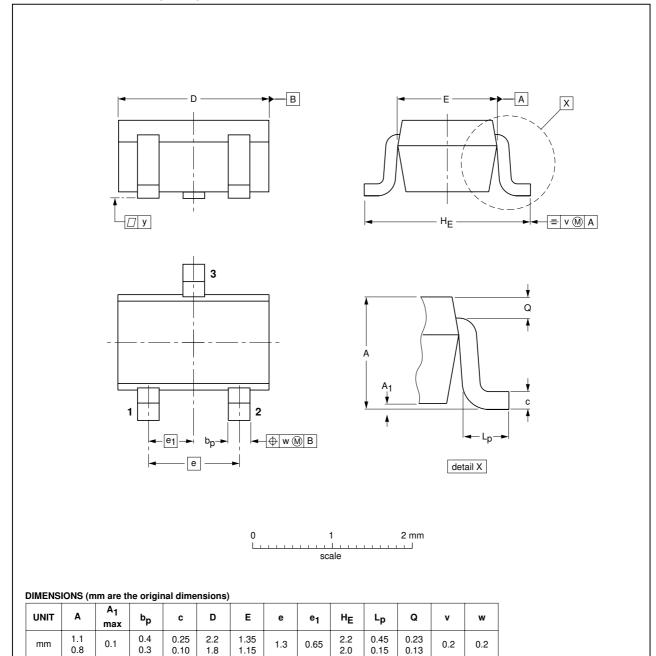
OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT346		TO-236	SC-59A		04-11-11 06-03-16	

PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTA144W series

Plastic surface-mounted package; 3 leads

SOT323



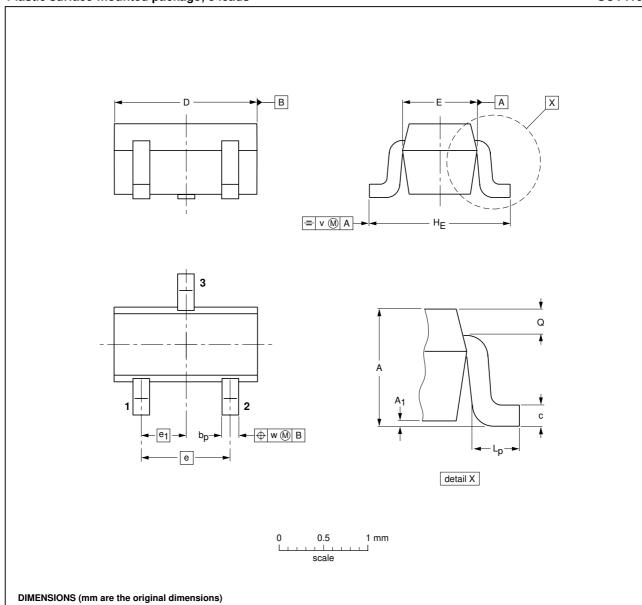
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION			JEITA		PROJECTION	ISSUE DATE	
SOT323			SC-70			04-11-04 06-03-16	

PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTA144W series

Plastic surface-mounted package; 3 leads

SOT416



UNI	ТА	A ₁ max	bp	С	D	E	е	e ₁	HE	Lp	ø	v	w
mn	0.95 0.60	0.1	0.30 0.15	0.25 0.10	1.8 1.4	0.9 0.7	1	0.5	1.75 1.45	0.45 0.15	0.23 0.13	0.2	0.2

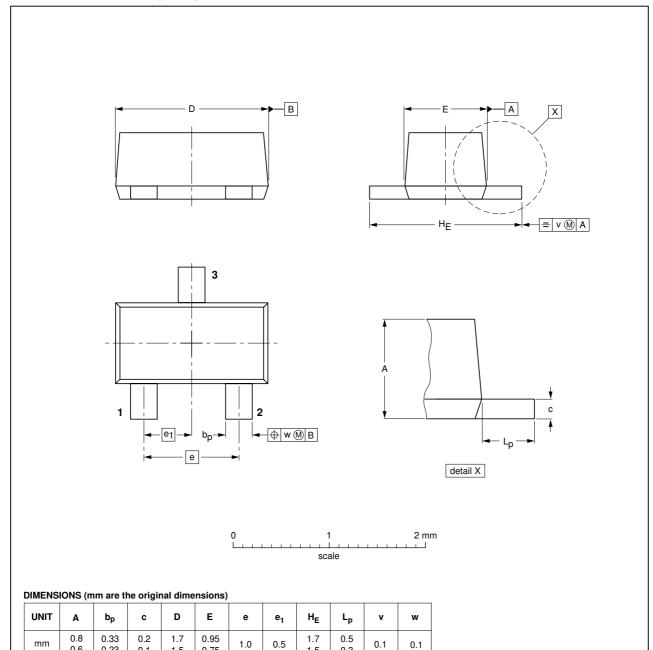
OUTLINE		EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT416			SC-75			04-11-04 06-03-16

PNP resistor-equipped transistors; $R1 = 47 \text{ k}\Omega$, $R2 = 22 \text{ k}\Omega$

PDTA144W series

Plastic surface-mounted package; 3 leads

SOT490



OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT490			SC-89			05-07-28 06-03-16	

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1.5

0.6

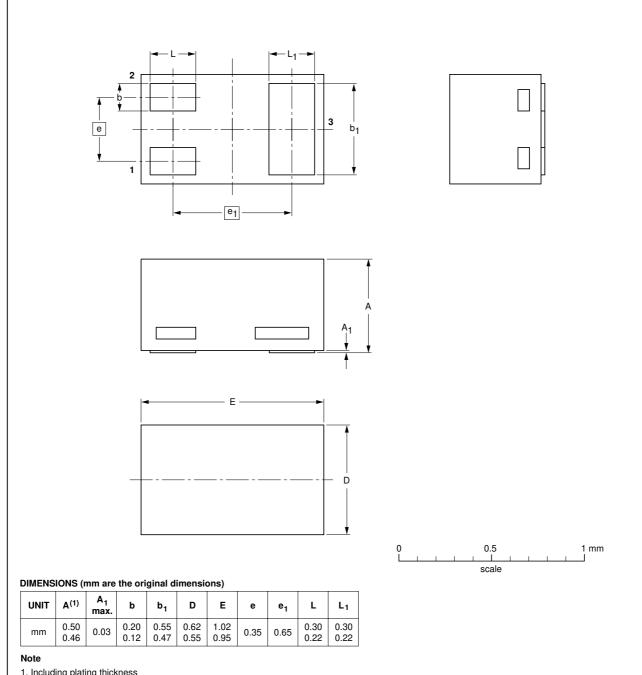
0.23

PNP resistor-equipped transistors; $R1 = 47 \text{ k}\Omega$, $R2 = 22 \text{ k}\Omega$

PDTA144W series

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883



1. Including plating thickness

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT883			SC-101			03-02-05 03-04-03

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PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTA144W series

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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Printed in The Netherlands R75/07/pp14 Date of release: 2004 Aug 05 Document order number: 9397 750 13662

